# 2SC3856

(Ta=25°C)

### Silicon NPN Triple Diffused Planar Transistor (Complement to type 2SA1492)

# **Application:** Audio and General Purpose

■Absolute maximum ratings (Ta=25°C)

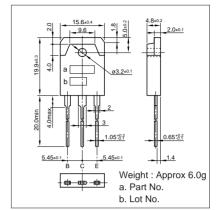
Зуптрог	Raurigs	Unit
Vсво	200	V
VCEO	180	V
VEBO	6	V
Ic	15	А
Ів	4	А
Pc	130(Tc=25°C)	W
Tj	150	°C
Tstg	-55 to +150	°C

■Electrical Characteristics
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Symbol	Conditions	Ratings	Unit
Ісво	Vcb=200V	100max	μΑ
<b>І</b> ЕВО	VEB=6V	100max	μΑ
V(BR)CEO	Ic=50mA	180min	V
hfe	Vce=4V, Ic=3A	50min*	
Vce(sat)	Ic=5A, IB=0.5A	2.0max	V
fт	Vce=12V, Ie=-0.5A	20typ	MHz
Сов	Vcb=10V, f=1MHz	300typ	pF
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\*hfe Rank \overline{O}(50 to 100), P(70 to 140), Y(90 to 180)

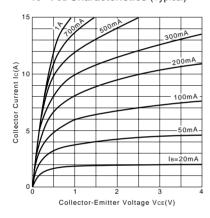
# External Dimensions MT-100(TO3P)



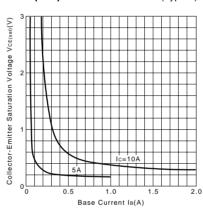
# ■Typical Switching Characteristics (Common Emitter)

Vcc (V)	Rι (Ω)	Ic (A)	V <sub>BB1</sub> (V)	VBB2 (V)	I <sub>B1</sub> (A)	IB2 (A)	ton (µs)	tstg (µs)	tf (µs)
40	4	10	10	-5	1	-1	0.5typ	1.8typ	0.6typ

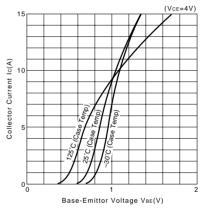
# Ic-VcE Characteristics (Typical)



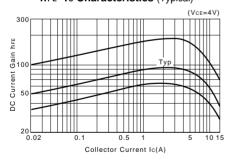
VcE(sat)-IB Characteristics (Typical)



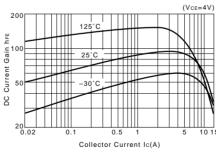
Ic-VBE Temperature Characteristics (Typical)



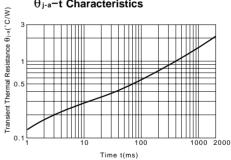
hfe-Ic Characteristics (Typical)



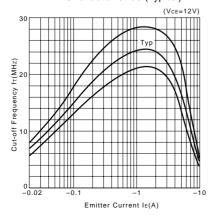
hfe-Ic Temperature Characteristics (Typical)



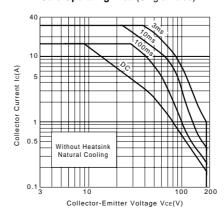
 $\theta_{j-a}$ -t Characteristics



fT-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



Pc-Ta Derating

